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# Impact of supporting nanometric membranes on the thermo-optical dynamics of individual plasmonic nanodisks

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The thermal dynamics and transient optical response of individual gold nanodisks supported on thin silicon nitride membranes were investigated using optical time-resolved pump–probe spectroscopy and finite-element modeling. The effect of reducing the membrane thickness from 50 nm to 15 nm on the nanodisk thermal dynamics was explored. A significant deceleration of the nanodisk cooling kinetics was observed, and linked to a quasi-two-dimensional heat diffusion process within the 15 nm thick membrane, without detectable modification of its thermal conductivity. Systematic measurements involving different optical probe wavelengths additionally revealed the contribution of indirect membrane heating to the measured time-resolved signals, an effect particularly pronounced in the spectral range where direct optical heating of the nanodisk induces minimal ultrafast modifications of its extinction cross-section.

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## 1. Introduction

Exploring the intricacies of heat transfer at nanometric scales is a fundamental challenge with wide-reaching technological applications in domains such as nanoelectronics, thermoelectricity and photothermal therapies.<sup>1–5</sup> Achieving rapid cooling kinetics for densely packed nanometric electronic components is for instance a crucial requirement to prevent thermal damage, maintain operational efficiency, and advance the miniaturization of electronic devices. Nanoscale heat transfer exhibits distinct characteristics, with notably an increased significance of interfaces, which induce thermal resistances,<sup>6,7</sup> and an inapplicability of the Fourier diffusion picture when the considered length scales are smaller than the phonon mean free path, the average distance a phonon travels between two consecutive scattering events.<sup>8,9</sup> Time- and frequency-domain pump–probe optical spectroscopies constitute powerful tools to study nanoscale heat transfer in systems involving light-absorbing components. These methods generally rely on the optical creation of nanoscale temperature gradients within the investigated system (e.g. by illuminating it with strongly focused light beams or with stationary waves creating transient thermal gratings) and on the optical detection of the sub-

sequent thermal relaxation, based on the changes of optical properties that they induce.<sup>10–16</sup> The use of absorbing nanostructures confined in one (thin films and suspended membranes), two (nanowires and nanolines) or three dimensions (nanoparticles) and located in a transparent environment is highly relevant in this field, as these objects can be practically synthesized with sizes much smaller than the diffraction-limited ones of light beams. Therefore, they allow to achieve heating and probing volumes much smaller than in experiments on bulk materials, at the price of complications associated to the introduction of interfaces.<sup>17–26</sup>

Optical studies conducted on silicon membranes have for instance revealed that the room-temperature thermal conductivity of these 1D-confined systems is thickness-dependent and considerably reduced as compared to bulk values,<sup>27,28</sup> consistently with electrical measurements on silicon films and nanowires.<sup>29,30</sup> These observations can be attributed to a phonon mean free path diminishment due to boundary scattering at membrane surfaces. Utilizing small nanoparticles as nanoheaters offers the opportunity to collect quantitative insights into both the thermal conductance of their interface with their local environment and the modalities of heat propagation within this environment. Employing nanoparticles with optical responses exhibiting temperature-dependent resonant features has proved advantageous for sensitively probing nanoparticle heating.<sup>24,31,32</sup> This advantage occurs in particular for noble metal nanoparticles, whose absorption and scattering spectra are characterized by localized surface plasmon

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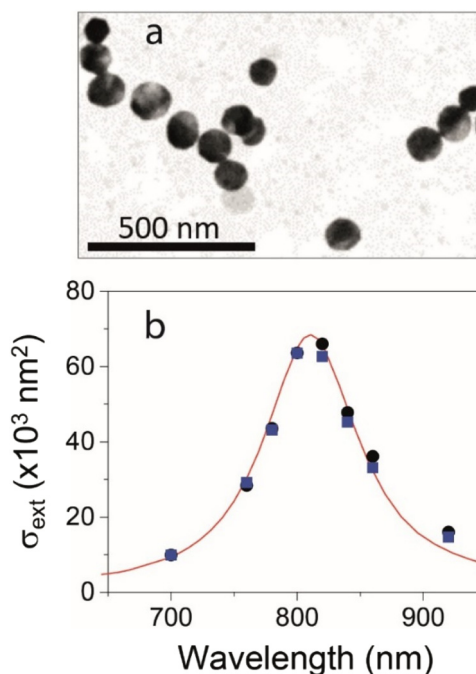
resonances (SPRs), sensitive to the temperature-induced changes in the dielectric properties of both the nanoparticles and their local environment.<sup>33</sup> In this context, conducting thermo-optical measurements on single plasmonic nanoparticles offers additional advantages for fundamental investigations of nanoscale heat transfer, because such measurements establish a precise correlation between the composition and morphological features of nanoparticles, their thermal dynamics, and the transient optical response they induce.<sup>32,34</sup>

While single-approaches have been used for two decades for studying the electronic and vibrational dynamics of metal nanoparticles,<sup>35,36</sup> they have only lately been applied to heat transfer investigations. We have recently reported optical investigations on the thermal coupling between a single, 3D-confined nanoheater (a gold nanodisk (ND)) and a bulk or 1D-confined substrate (thick sapphire substrate or suspended silica or silicon nitride membrane with  $\approx 50$  nm thickness).<sup>32,37</sup> The work presented here focuses on the case of single NDs supported on a notably thinner  $\text{Si}_3\text{N}_4$  membrane (15 nm thickness). A key difference with the previously investigated cases is the reduced time ( $\approx 0.5$  ns) required for heat to traverse the membrane thickness. This shorter time now falls within our experimentally accessible range of pump-probe delays (extending up to about 3 ns), enabling a more direct observation of finite-thickness thermal effects. We also measured the transient optical responses of membrane-supported single NDs with varying probe wavelength, an experimentally accessible parameter allowing to tune and disentangle the influences of ND/environment heating on the measured time-resolved signals.<sup>31</sup>

## 2. Results and discussion

### 2.1. Measured optical signals

Single-particle optical experiments were conducted on gold NDs deposited onto a 15 nm thick  $\text{Si}_3\text{N}_4$  membrane (see Methods for details about the synthesis and deposition procedures). The morphological distribution of Au NDs in the originating colloidal solution, mostly containing NDs with approximately circular sections, is illustrated by the transmission electron microscopy image shown in Fig. 1a. Spatial Modulation Spectroscopy (SMS) was first used to locate individual gold NDs post-deposition on the membrane surface and measure their extinction spectra. Fig. 1b showcases one of the measured extinction cross-section ( $\sigma_{\text{ext}}$ ) spectra. It displays a resonance associated to the ND in-plane dipolar surface plasmon resonance (SPR), with a  $\lambda_{\text{SPR}} = 810$  nm central position. For this ND,  $\sigma_{\text{ext}}$  presents a negligible sensitivity to the polarization of the incident light. This observation, consistent with a circular ND shape (but also with triangular or hexagonal ones), indicates the absence of a significant ellipticity of the ND section, which would lift the degeneracy of the two in-plane ND SPRs.<sup>38</sup> The measured quantitative  $\sigma_{\text{ext}}$  spectra could be well reproduced by optical Finite Element Modeling (FEM) simulations, using diameter values close to the  $(97 \pm 12)$  nm average ND diameter determined from electron microscopy

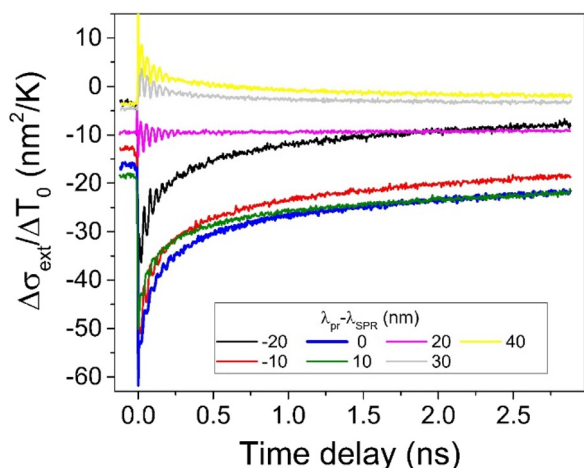


**Fig. 1** Electron microscopy characterization and single-particle optical spectroscopy of gold NDs. (a) Transmission electron microscopy image of NDs from the synthesized solution. (b) SMS-measured and FEM-modeled extinction spectra of a single gold ND deposited on a 15 nm thick silicon nitride membrane. The black circles and blue squares correspond to measurements performed with two orthogonal polarizations of the incident light. The red line corresponds to the result of a FEM simulation considering a circular ND with  $D = 93$  nm diameter and  $h = 9.6$  nm thickness.

observations and  $h \approx 10$  nm thicknesses. The  $\sigma_{\text{ext}}$  spectrum depicted in Fig. 1b was for instance modeled using  $D = 93$  nm and  $h = 9.6$  nm diameter and thickness values.

The exploration of the ultrafast dynamics of individual supported gold NDs following their sudden excitation was carried out through time-resolved pump-probe optical experiments, using various probe wavelengths  $\lambda_{\text{pr}}$ , as detailed in the Methods section. To precisely distinguish the influence of  $\lambda_{\text{pr}}$  from that of the variations of pump beam attributes (wavelength, spot size and fluence) during the course of the experiments, the measured transient extinction changes  $\Delta\sigma_{\text{ext}}$  were divided by the estimated initial ND temperature rise  $\Delta T_0$  (of the order of 10 K) following the partial absorption of each pump pulse and ND internal thermalization by electron-lattice energy exchanges.<sup>32</sup> Illustrative normalized transient extinction changes measured on a single ND are presented in Fig. 2. The measured  $\Delta\sigma_{\text{ext}}(t)$  dynamics exhibit the three characteristic features of the transient optical response of metal nanoparticles subsequent to their sudden optical excitation:<sup>33,39</sup> (1) an initial peak linked to ND optical excitation and internal thermalization on few picosecond time scales, (2) oscillations associated to ND acoustic vibrations, showing here a damping time of a few hundreds of ps, and (3) a relaxation over a nanosecond time scale, reflecting the ND cooling dynamics, *i.e.* the





**Fig. 2** Probe wavelength effect on the time-resolved signals measured on a gold ND deposited on a 15 nm thick silicon nitride membrane. The figure shows illustrative time-resolved extinction cross-section changes measured with different probe wavelengths  $\lambda_{\text{pr}}$  on the ND whose extinction spectrum is shown in Fig. 1 ( $\lambda_{\text{SPR}} = 810$  nm), divided by  $\Delta T_0$ , the estimated ND temperature rise following its interaction with a pump pulse with  $\lambda_{\text{pp}} = \lambda_{\text{pr}}/2$  wavelength and  $\approx 0.5 \text{ J m}^{-2}$  fluence.

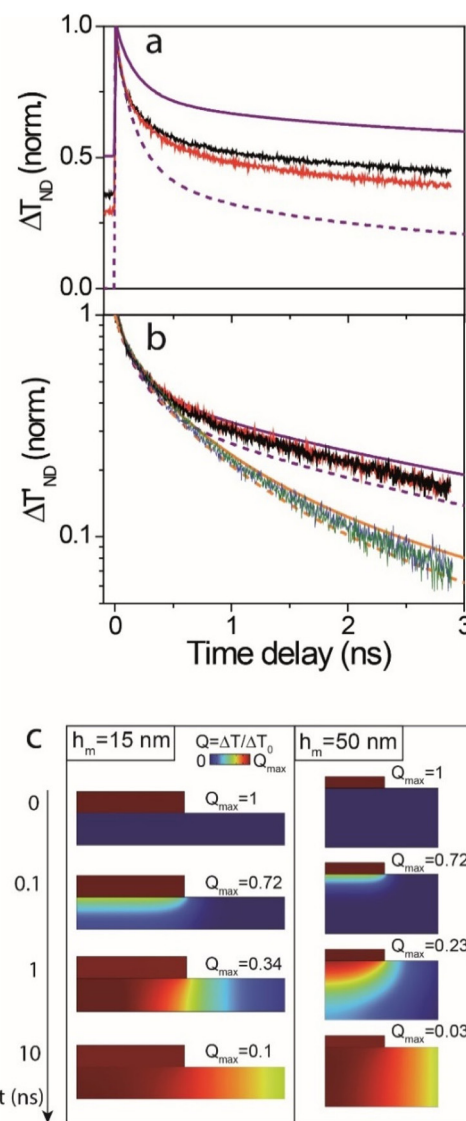
dissipation into the ND environment of energy deposited in the investigated nanoparticle through partial absorption of the pump pulses.

Fig. 2 shows that the average value of the measured signals differs from zero at negative time delays. This feature indicates that the  $T_{\text{rep}} = 1/f_{\text{rep}} = 12.5$  ns time separating two successive pump pulses is not sufficient for complete dissipation far away from the ND of the energy injected by each pump pulse. Additionally, Fig. 2 also illustrates the strong and different  $\lambda_{\text{pr}}$ -dependencies of the amplitudes of the oscillating and thermal components of the signals. Probing at the SPR central position ( $\lambda_{\text{pr}} \approx \lambda_{\text{SPR}}$ ) leads to a large thermal component and to a nearly undistinguishable oscillatory component. Conversely, the signals measured using  $\lambda_{\text{pr}} - \lambda_{\text{SPR}} = 20\text{--}30$  nm present marked oscillations, while remaining nearly constant after damping of the oscillations (indicating a weak sensitivity to ND heating). This work focuses on the thermal components of the measured time-resolved signals, which were deduced from the raw signals by subtraction of their oscillating part, fitted by a sum of 1–3 damped sinusoids (each corresponding to a distinct detected vibrational mode).<sup>38,40</sup>

## 2.2. ND cooling dynamics

Investigations of the cooling dynamics of single metal nano-objects using time-resolved optical experiments are most effectively performed when using  $\lambda_{\text{pr}} \approx \lambda_{\text{SPR}}$ , as these probing conditions have been established to respectively maximize and minimize the sensitivities of time-resolved signals to heating of the nanoparticles and of their local environment. Such a  $\lambda_{\text{pr}}$  choice thus ensures that the temporal variations of the measured signals reflect those of the ND temperature rise  $\Delta T_{\text{ND}}(t)$ .<sup>31</sup> The normalized thermal components of the signals

measured on two distinct NDs in these specific conditions are shown in Fig. 3a. The normalized  $\Delta T_{\text{ND}}(t)$  dynamics of the two NDs exhibit slightly different average values at negative times (0.3 and 0.35). These values significantly exceed the  $\approx 0.1$  ones



**Fig. 3** Thermal dynamics of single Au NDs on thin  $\text{Si}_3\text{N}_4$  membranes. (a) Normalized  $\Delta T_{\text{ND}}(t)$  temperature rise dynamics measured on two distinct gold NDs supported by a 15 nm thick  $\text{Si}_3\text{N}_4$  membrane (black and red traces) and  $\Delta T_{\text{ND}}(t)$  dynamics simulated with (solid purple line) and without (dashed line) inclusion of repetition effects in the modeling (see main text for details). (b) Signals deduced from those of panel (a) after subtraction of their average values at negative time delays  $\Delta T'_{\text{ND}}(t) = \Delta T_{\text{ND}}(t) - \Delta T_{\text{ND}}(0^-)$  and normalization, presented on a logarithmic scale (same color code). The signals previously measured for two different NDs (blue and green traces) and modeled (solid and dashed orange lines) for a 50 nm thick membrane are also shown for comparison.<sup>37</sup> (c) Temperature profiles computed using FEM at time delays of 0, 0.1, 1 and 10 ns after the sudden optical excitation of a ND located on a 15 nm (left) or 50 nm (right) thick  $\text{Si}_3\text{N}_4$  membrane. The  $Q = \Delta T/\Delta T_0$  ratios are plotted using a color scale ranging from 0 to  $Q_{\text{max}}$ , which corresponds to the  $Q$  value inside the ND at each considered time (indicated).

measured on NDs stemming from the same colloidal solution but deposited on a thicker (50 nm thick) Si<sub>3</sub>N<sub>4</sub> membrane.<sup>37</sup> This considerable increase of the normalized value of  $\Delta T_{\text{ND}}(0^-)$ , *i.e.*, the temperature rise at the end of the interval separating two successive pump pulses, constitutes a first indication of the slowing down of ND cooling dynamics with decreasing membrane thickness, discussed in more detail below.

The ND cooling dynamics shown in Fig. 3a become very similar if temperature rises are defined relatively to the ND temperature before each pump excitation, rather than to that in the absence of any excitation. This is shown in Fig. 3b, where the normalized  $\Delta T'_{\text{ND}}(t) = \Delta T_{\text{ND}}(t) - \Delta T_{\text{ND}}(0^-)$  dynamics are plotted alongside previous measurements on NDs supported on a 50 nm Si<sub>3</sub>N<sub>4</sub> membrane,<sup>37</sup> highlighting  $\Delta T'_{\text{ND}}(t)$  strong dependence on membrane thickness. The  $\Delta T'_{\text{ND}}(t)$  dynamics measured for NDs deposited on 15 nm thick Si<sub>3</sub>N<sub>4</sub> membranes exhibit a non-exponential behavior, indicating that they are not solely ruled by heat transfer at the ND-membrane interface.<sup>21</sup> While they resemble those previously recorded on 50 nm thick membrane at <0.5 ns delays, they become much slower at larger delays (Fig. 3b), presenting for example 3× higher normalized  $\Delta T'_{\text{ND}}(t)$  values after 2.7 ns, the largest pump–probe delays achievable in our experiments.

The observed membrane thickness effect on  $\Delta T'_{\text{ND}}(t)$  dynamics can be qualitatively understood by considering the solutions of the heat equation  $\frac{\partial T}{\partial t} = \alpha_m \nabla^2 T$  (with  $\alpha_m$  the thermal diffusivity of the membrane) for a point source located at (0,0,0) on the surface of a membrane of thickness  $h_m$  ( $0 < z < h_m$ ) and of infinite lateral extension, initially at a uniform temperature, with insulation boundary conditions on the membrane surfaces ( $\frac{\partial T}{\partial z}(z=0) = \frac{\partial T}{\partial z}(z=h_m) = 0$ ). The time- and position-dependent temperature rise  $\Delta T$  in the membrane can be deduced from the solution of the heat equation in a 3D semi-infinite medium  $\Delta T(x,y,z,t) \propto t^{-3/2} e^{-\frac{(x^2+y^2+z^2)}{4\alpha_m t}}$  by adding the effect of an infinity of virtual sources at positions  $(0,0,2nh_m)$ , with  $n$  an integer,<sup>41,42</sup> and writes

$$\Delta T(x,y,z,t) \propto \frac{1}{t^{3/2}} e^{-\frac{(x^2+y^2)}{4\alpha_m t}} \sum_{n=-\infty}^{\infty} e^{-\frac{(z-2nh_m)^2}{4\alpha_m t}} \quad (1)$$

The temperature rise  $\Delta T$  is thus obtained by multiplying the solution for a point source at the surface of an infinite 2D medium (Gaussian distribution with a width increasing as  $t^{1/2}$ ) by the solution for a point source on a 1D finite slab (Jacobi theta function). At short time scales ( $\alpha_m t \ll h_m^2$ ), the sum is dominated by its  $n = 0$  term, and  $\Delta T$  approximately coincides with the solution for a 3D semi-infinite substrate, with a  $t^{-3/2}$  dependence at the source position. Conversely, at long time scales ( $\alpha_m t \gg h_m^2$ , so that the sum can be approximated by an integral),  $\Delta T \propto \frac{1}{t^{3/2}} e^{-\frac{(x^2+y^2)}{4\alpha_m t}}$ , which corresponds to a uniform temperature along the membrane thickness and a lateral 2D diffusion of heat. The transition between the two regimes

occurs for  $\alpha_m t \approx h_m^2$ , *i.e.*, for a Si<sub>3</sub>N<sub>4</sub> membrane ( $\alpha_m = 5 \times 10^{-7} \text{ m}^2 \text{ s}^{-1}$ , assuming a  $\Lambda_m = 1 \text{ W m}^{-1} \text{ K}^{-1}$  thermal conductivity) at times of the order of 0.5 ns and 5 ns for  $h_m = 15 \text{ nm}$  and  $h_m = 50 \text{ nm}$ , respectively. Although based on a simplified analysis, the 0.5 ns transition time for a  $h_m = 15 \text{ nm}$  membrane corresponds well with that at which experimental signals measured on the two membranes start to significantly deviate (Fig. 3b).

A more quantitative modeling of ND cooling dynamics necessitates to avoid the simplifications made in the previous analysis and to take into account the actual ND geometry, the non-instantaneous release of heat in the supporting membrane and the periodical character of ND optical excitation. To accomplish this, numerical simulations of the cooling dynamics of supported NDs were conducted using a previously described frequency-domain thermal model<sup>32,37</sup> (note that an analytical treatment of the problem, such as that reported for stacked layers with infinite lateral extension,<sup>19,43</sup> is much more challenging here because of the mixed boundary conditions at the membrane surface). This model is based on the computation, using FEM, of the frequency-dependent thermal response of a supported ND, *i.e.*, the spatial distribution of the amplitude and phase of the temperature oscillations following a sinusoidal excitation, which summarizes the ND thermal response to any time-dependent excitation  $q(t)$ .<sup>19,44</sup> In such calculations, the amplitude of thermal oscillations decays in a frequency-dependent manner around heated regions, over a characteristic length scale given by the heat penetration length  $L_p = \sqrt{\frac{\alpha_m}{\pi f}}$  (with  $L_p \approx 40 \text{ nm}$  in silicon nitride when  $f = f_{\text{rep}} = 80 \text{ MHz}$ ). This implies that for ND excitation by a train of Dirac pulses  $q(t) \propto \sum_{n=-\infty}^{+\infty} \delta(t - nT_{\text{rep}})$ , which corresponds to a  $\tilde{q}(f) \propto \sum_{n=-\infty}^{+\infty} \delta(f - nf_{\text{rep}})$  frequency content, the membrane properties (size, modalities of heat exchanges at the membrane ends and with air, which are poorly known in our experiments) at scales much larger than  $L_p$  only affect the average heating (0-frequency component). Uncertainties about the large-scale membrane properties are therefore not limiting for a quantitative analysis of the  $\Delta T'_{\text{ND}}(t)$  dynamics. Here, a Si<sub>3</sub>N<sub>4</sub> membrane with  $D_m = 2 \mu\text{m}$  diameter (much smaller than the actual membrane size, thus largely reducing computational times) with fixed temperature boundary conditions (BCs) at its end and insulating BCs on its circular faces was used, as in our previous work.<sup>37</sup>  $D = 100 \text{ nm}$  and  $h = 10 \text{ nm}$  values were used for ND diameter and thickness. These dimensions roughly correspond to the average ones deduced from electron microscopy observations and SMS characterization on NDs from the colloidal solution used.

The fitting parameters of our model are the thermal conductance  $G$  of the Au–Si<sub>3</sub>N<sub>4</sub> interface and the thermal conductivity  $\Lambda_m$  of Si<sub>3</sub>N<sub>4</sub> (whose previous measurements have led to scattered results<sup>17,45–49</sup>). The  $\Delta T'_{\text{ND}}(t)$  dynamics of NDs deposited on 15 nm thick membranes can be accurately reproduced using the same values of  $G$  and  $\Lambda_m$  as in the case of 50 nm thick membranes,<sup>37</sup> namely  $G = 150 \text{ MW m}^{-2} \text{ K}^{-1}$  and





$\Lambda_m = 1 \text{ W m}^{-1} \text{ K}^{-1}$ . This is illustrated in Fig. 3b, which shows the  $\Delta T'_{\text{ND}}(t)$  dynamics computed for NDs supported on  $\text{Si}_3\text{N}_4$  membranes using these  $G$  and  $\Lambda_m$  values (solid purple and orange lines). The excellent reproduction of experimental signals at  $<0.5$  ns delays (at which  $\Delta T'_{\text{ND}}$  dynamics are mostly controlled by  $G$  and  $\Lambda_m$ <sup>37</sup>) using  $G = 150 \text{ MW m}^{-2} \text{ K}^{-1}$  and  $\Lambda_m = 1 \text{ W m}^{-1} \text{ K}^{-1}$  indicates that these values constitute accurate estimations of  $G$  and  $\Lambda_m$  (with uncertainties of the order of 10%) for both 50 and 15 nm thick membranes. The slight shift between the measured and modeled  $\Delta T'_{\text{ND}}(t)$  dynamics at  $>1$  ns delays could have several causes, including a slight difference between the nominal and actual values of the membrane thickness. Regarding the  $\Delta T_{\text{ND}}(t)$  dynamics (Fig. 3a), one can observe that the  $\Delta T_{\text{ND}}(0^-)$  temperature rises predicted by the model are higher by about 50% than the measured ones, similarly to previous observations for  $\approx 50$  nm thick membranes.<sup>37</sup> This difference, which would increase with the use in the modeling of larger  $D_m$  values, closer to the actual membrane size, suggests that the thermal coupling of the membrane with ambient air taking place at the top and bottom planar surfaces of the membrane (not included in the modeling where dissipation only occurs at the membrane lateral ends) plays a significant role in large-scale membrane cooling.

The deduction of similar  $\Lambda_m$  values from the analysis of the  $\Delta T'_{\text{ND}}(t)$  dynamics measured on 50 nm and 15 nm thick membranes stands in stark contrast to findings on silicon membranes of similar thickness, whose thermal conductivity was seen to be strongly thickness-dependent and up to  $\approx 5$  times smaller than the bulk silicon one.<sup>28</sup> This disparity in the thickness-dependence of the thermal properties of  $\text{Si}_3\text{N}_4$  and Si membranes can be attributed to the large difference between the heat conductivity and phonon mean free paths of these two materials in the bulk form. Indeed, amorphous media such as silica and silicon nitride have a  $\approx 1$  nm room temperature phonon mean free path, while in crystalline silicon a large fraction of phonons have  $>100\times$  longer mean free paths.<sup>15,22,50</sup> Experimental observations are thus consistent with the fact that membrane thickness reduction in the tens of nm range should significantly diminish the mean free path of phonons in Si, but not in  $\text{Si}_3\text{N}_4$ .

The  $\Delta T_{\text{ND}}(t)$  dynamics were also computed in the case of ND excitation by a single pump pulse, which corresponds to discarding accumulation effects (dashed lines in Fig. 3). These complementary calculations allow to appreciate the respectively strong and relatively weak influences of a repeated ND excitation on the  $\Delta T_{\text{ND}}(t)$  and  $\Delta T'_{\text{ND}}(t)$  dynamics. They also enable a clear visualization of the transition from a 3D to a 2D heat diffusion in a membrane heated by a source located at its surface, discussed above based on analytical expressions. This transition is illustrated in Fig. 3c, which presents snapshots of the temperature profiles computed for single pulse excitation of a ND positioned on a 15 nm or 50 nm thick membrane. At  $t = 0.1$  ns heat diffusion presents a distinct 3D character, with only regions less than 10 nm away from the ND being significantly heated. Conversely, at  $t = 1$  ns the temperature profile has become independent of depth for a 15 nm thick mem-

brane (but not for a 50 nm thick one). At  $t = 10$  ns (a delay exceeding the experimentally accessible ones) diffusion has evolved into a 2D process in both cases, resulting in depth-independent temperature distributions.

### 2.3. Sensitivity of time-resolved signals to ND and membrane heating

The analysis of time-resolved signals measured by varying the probe wavelength  $\lambda_{\text{pr}}$  (Fig. 2) necessitates a more complete modeling addressing not only the cooling dynamics of membrane-supported NDs, but also the transient changes of ND extinction cross-section  $\sigma_{\text{ext}}$  that they induce. A useful starting point for interpreting these measurements is the situation of uniform temperatures in both the ND and its local supporting membrane, noted  $T_{\text{ND}}$  and  $T_m$ .<sup>24,31</sup> In this case, simplified as compared to the experimental one where only the ND temperature can be reasonably considered as uniform (because of the high thermal conductivity of gold), the extinction changes induced by small modifications of  $T_{\text{ND}}$  and  $T_m$  can be written as

$$\Delta\sigma_{\text{ext}}(\lambda_{\text{pr}}) = A_{\text{ND}}(\lambda_{\text{pr}})\Delta T_{\text{ND}} + A_m(\lambda_{\text{pr}})\Delta T_m \quad (2)$$

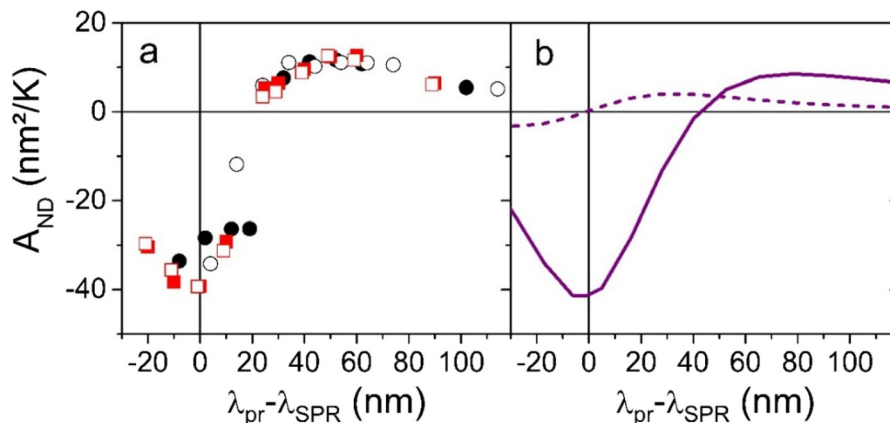
with

$$\begin{aligned} A_{\text{ND}}(\lambda_{\text{pr}}) &= \frac{\partial\sigma_{\text{ext}}}{\partial\varepsilon_1}(\lambda_{\text{pr}}) \frac{\partial\varepsilon_1}{\partial T_{\text{ND}}}(\lambda_{\text{pr}}) + \frac{\partial\sigma_{\text{ext}}}{\partial\varepsilon_2}(\lambda_{\text{pr}}) \frac{\partial\varepsilon_2}{\partial T_{\text{ND}}}(\lambda_{\text{pr}}) \\ A_m(\lambda_{\text{pr}}) &= \frac{\partial\sigma_{\text{ext}}}{\partial\varepsilon_m}(\lambda_{\text{pr}}) \frac{\partial\varepsilon_m}{\partial T_m} \end{aligned} \quad (3)$$

where  $\varepsilon = \varepsilon_1 + i\varepsilon_2$  is the dielectric function of the gold ND, and  $\varepsilon_m$  that of the membrane, assumed to be real and dispersionless. The  $A_{\text{ND}}$  and  $A_m$  coefficients introduced in eqn (2) and (3) quantify the sensitivity of the ND extinction cross-section to ND and membrane heating, respectively. The derivatives of  $\sigma_{\text{ext}}$  relatively to  $\varepsilon_1$ ,  $\varepsilon_2$  and  $\varepsilon_m$  involved in their definition (eqn (3)) can be computed using optical FEM modeling, which allows to estimate the change of ND extinction cross-section (Fig. 1b) following slight modifications of these parameters. These calculations show that the  $\frac{\partial\sigma_{\text{ext}}}{\partial\varepsilon_m}$  derivative vanishes for  $\lambda_{\text{pr}} \approx \lambda_{\text{SPR}}$ , which explains the possibility of selectively probing  $\Delta T_{\text{ND}}$  in this wavelength range.<sup>31</sup> The temperature-dependence of gold dielectric function has been previously measured and modeled.<sup>51–57</sup> We used here the data from ref. 53, as in our recent works.<sup>32,37</sup>  $\varepsilon_m = 4.12$  and  $\frac{\partial\varepsilon_m}{\partial T_m} = 10^{-4} \text{ K}^{-1}$  were used for  $\text{Si}_3\text{N}_4$ , consistently with previous measurements.<sup>58</sup>

As each pump pulse deposits energy in the ND only, the extinction modification immediately following ND excitation and internal thermalization is solely due to an increase of ND temperature. This enables experimental extraction of the wavelength-dependent  $A_{\text{ND}}$  coefficient appearing in eqn (2) and (3), by evaluating the variation of the thermal components of  $\Delta\sigma_{\text{ext}}(t)/\Delta T_0$  (Fig. 2) following ND excitation by the pump pulse. The  $A_{\text{ND}}$  spectra deduced from measurements on two NDs are plotted in Fig. 4a, as a function of  $\lambda_{\text{pr}} - \lambda_{\text{SPR}}$  to facilitate the comparison between the different measurements, as





**Fig. 4** Sensitivity of ND extinction cross-section to ND heating. (a) Sensitivity deduced from time-resolved experiments (see eqn (2) and (3) for  $A_{ND}$  definition). The experimental results were obtained on two distinct NDs (black circles and red squares) for two orthogonal polarizations of the probe beam (solid and hollow symbols). (b) Sensitivity computed using FEM optical simulations and temperature dependence of gold dielectric function from ref. 53 (solid purple line). The computed sensitivity to  $\text{Si}_3\text{N}_4$  membrane heating is also shown for comparison (dashed line).

$\lambda_{SPR}$  slightly varies from one ND to another and presents for some NDs a slight polarization dependence, signature of a small ND elongation.<sup>38</sup> They are similar for the two investigated NDs and polarizations. ND heating produces a negative  $\sigma_{ext}$  variation for  $\lambda_{pr} - \lambda_{SPR} < 20$  nm and a positive one for higher  $\lambda_{pr}$  values. The maximal  $|A_{ND}|$  value, obtained for  $\lambda_{pr} \approx \lambda_{SPR}$ , is of the order of 40  $\text{nm}^2 \text{K}^{-1}$ . The  $A_{ND}$  spectra resemble those previously measured on lithographed NDs,<sup>32</sup> with however different maximal  $|A_{ND}|$  values, which can be ascribed to the use of NDs with different dimensions in the two studies.

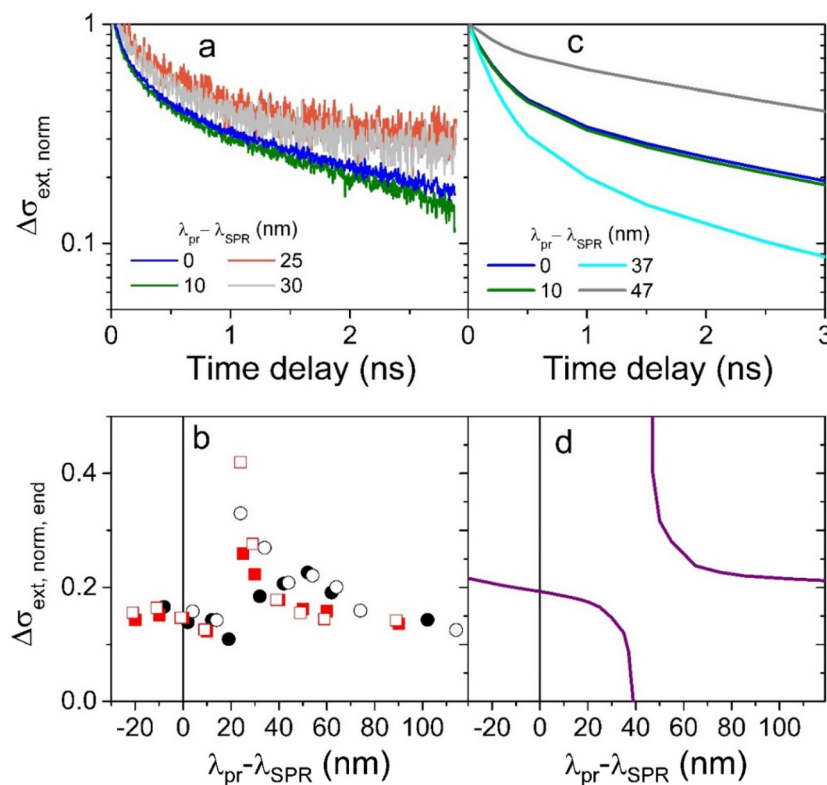
Due to the large uncertainties on the temperature dependence of gold dielectric function (eqn (3)), whose measurement has led to scattered results,<sup>51–57</sup> obtaining a precise match between the measured and modeled  $A_{ND}$  spectra is hardly achievable. Nevertheless, the  $A_{ND}$  spectrum computed based on eqn (3), shown in Fig. 4b, presents spectral variations and absolute values similar to the measured ones, mostly differing by the spectral position of the  $A_{ND}$  sign change, which is located further away from  $\lambda_{SPR}$  in the simulation case. The general shape of the  $A_{ND}$  spectrum results from the much larger temperature-dependence of  $\epsilon_2$  (which mostly influences SPR width) as compared to  $\epsilon_1$  (which mostly impacts SPR position) in eqn (3). ND heating thus mostly induces a broadening of SPR, leading to a decrease of  $\sigma_{ext}$  close to  $\lambda_{SPR}$  and to an increase further away from  $\lambda_{SPR}$ . The computed  $A_m$  spectrum is also shown in Fig. 4b. Its spectral shape largely differs from the  $A_{ND}$  one, which is due to the fact that membrane heating mostly affects SPR position.  $|A_m|$  is usually much smaller than  $|A_{ND}|$  (Fig. 4b). However, this is not the case in the  $\approx 20$  nm broad spectral range around the wavelength where  $A_{ND}$  vanishes, suggesting that measurements with  $\lambda_{pr}$  in this spectral range should be very significantly affected by membrane heating.

Fig. 5a shows the  $\Delta\sigma_{ext,norm}(t)$  dynamics measured for different  $\lambda_{pr}$  values (obtained by dividing  $\Delta\sigma_{ext}(t)$  by its initial value) do not overlap. As  $\lambda_{pr}$  is increased on the red flank of the resonance, the  $\Delta\sigma_{ext,norm}(t)$  dynamics become initially

slightly faster ( $\lambda_{pr} - \lambda_{SPR} = 10$  nm) and then much slower ( $\lambda_{pr} - \lambda_{SPR} = 25$ –30 nm). A complementary illustration of the  $\lambda_{pr}$ -dependence of the  $\Delta\sigma_{ext,norm}(t)$  is shown in Fig. 5b, where the  $\Delta\sigma_{ext,norm}$  value at the maximal pump-probe delay (2.7 ns) is plotted as a function of  $\lambda_{pr}$ . While 0.15 values are observed for most  $\lambda_{pr}$  values, significantly larger values, up to 0.45 (corresponding to much slower dynamics) are observed for  $\lambda_{pr} - \lambda_{SPR} = 20$ –30 nm. This  $\lambda_{pr}$ -dependence of the  $\Delta\sigma_{ext,norm}(t)$  dynamics indicates that the transient ND optical response is not simply proportional to  $\Delta T_{ND}(t)$  when  $\lambda_{pr} \neq \lambda_{SPR}$ , especially when the sensitivity to ND heating is small and changes sign ( $\lambda_{pr} - \lambda_{SPR} = 20$ –30 nm, Fig. 4a), and strongly suggests that  $\Delta\sigma_{ext}$  is significantly affected by environment heating.

Comparison of the measured signals with the predictions of a complete thermo-optical model taking into account the inhomogeneous and time-dependent temperature rise inside the membrane is useful to fully demonstrate this hypothesis. The  $\Delta\sigma_{ext}(t)$  dynamics were thus simulated using the two-step modeling procedure discussed in ref. 31. It basically consists in complementing the purely thermal FEM computations discussed above, which provide the spatially- and time-dependent temperature rise profiles in the ND and the membrane, with optical FEM simulations estimating the temporal evolution of the ND extinction cross-section  $\sigma_{ext}$ . To do so,  $\sigma_{ext}$  was recalculated at various delays using dielectric functions modified in a spatially-dependent way, as (considering the example of the membrane one)  $\Delta\epsilon_m(\vec{r}, t) = \frac{\partial\epsilon_m}{\partial T_m} \Delta T_m(\vec{r}, t)$ . The predictions of the model regarding the  $\Delta\sigma_{ext,norm}(t)$  dynamics and its value after 3 ns are shown in Fig. 5c and d. The trends observable in these plots are very close to those of the experimental results, shown in Fig. 5a and b. In particular, the modeled results also feature a considerable slow-down of the dynamics (associated with a much larger final  $\Delta\sigma_{ext,norm}$  value) for probe wavelengths slightly higher than that at which  $A_{ND}$  vanishes. Additionally, the model also predicts much faster dynamics at





**Fig. 5** Influence of Si<sub>3</sub>N<sub>4</sub> membrane heating on the dynamics of transient ND extinction changes. (a) Examples of normalized thermal components of  $\Delta\sigma_{\text{ext}}$  measured on a single ND using different  $\lambda_{\text{pr}}$  values. (b) Average value of the normalized extinction change measured at 2.7 ns pump-probe delay (maximal delay in the experiments) for different NDs and polarizations. The same color code as in Fig. 4 was used. (c) Examples of normalized  $\Delta\sigma_{\text{ext}}$  changes FEM-computed using different  $\lambda_{\text{pr}}$  values. (d) Normalized extinction change after 3 ns computed using FEM.

slightly lower wavelength, an effect which could not be observed experimentally (essentially because the raw signals measured in this range are difficult to analyze, as they present strong oscillations and low-amplitude thermal components).

### 3. Conclusion

The thermo-optical dynamics of gold NDs supported on a nanometric Si<sub>3</sub>N<sub>4</sub> membrane were investigated both experimentally and numerically in this work. Decrease of the membrane thickness from 50 nm to 15 nm was seen to considerably slow down the ND cooling dynamics, and to increase its average heating for periodical pulsed excitation. This effect can be ascribed to the evolution of heat diffusion in the membrane from a 3D process to a 2D one after about 0.5 ns, the time required for heat to propagate over 15 nm in Si<sub>3</sub>N<sub>4</sub>. The significant heating of the membrane induced by its small thickness and the high (for a solid material) temperature-dependence of the Si<sub>3</sub>N<sub>4</sub> refractive index also allowed us to demonstrate the dependence of the ND transient optical response on probe wavelength. Strong variations of the time dependence of this transient response were in particular observed in the narrow wavelength range where environment contribution becomes of the order of (or even larger than) the

ND heating contribution. These results could be useful for applications requiring to minimize the cooling kinetics of nanostructures or for local probing of temperature or thermal properties of thin membranes using metal nanoparticles as thermometers. The extension of this work to situations involving nanoparticle size and/or membrane thickness smaller than phonon mean free paths in the membrane may also improve the fundamental understanding of nanoscale heat transport.

### 4. Methods

#### 4.1. ND synthesis and deposition

The synthesis of Gold NDs was performed in aqueous solution in presence of the cetyltrimethylammonium bromide (CTAB) surfactant, following an already published protocol.<sup>37,59</sup> Gold nanoplates were first synthesized by adapting a protocol initially used to produce triangular nanoplates,<sup>60</sup> using modified concentrations of the reactants in the growth solution (CTAB 0.1 M, HAuCl<sub>4</sub> 0.7 mM and ascorbic acid 1.6 mM), yielding nanoplates with  $\approx 90\%$  hexagonal and  $\approx 10\%$  triangular sections. Au NDs were subsequently obtained by smoothing the vertices and edges of the nanoplates through mild oxidation using the Au(III)/CTAB oxidant complex, as detailed



elsewhere.<sup>61,62</sup> Deposition of the NDs for single-particle optical investigations was performed on a 15 nm thick silicon nitride ( $\text{Si}_3\text{N}_4$ ) membrane patterned into  $100 \times 100 \mu\text{m}$  apertures, etched in a 200 nm thick support mesh (Ted Pella). The immobilization of NDs on these substrates was conducted by depositing a drop of highly diluted gold ND solution which was subsequently left to dry, leading to a low density of deposited NDs ( $<1$  ND per  $\mu\text{m}^2$ ), as required for far-field single-particle optical studies. Multiple thorough ethanol rinses followed by a UV/ozone treatment were administered to minimize the presence of organic residues.<sup>63</sup>

#### 4.2. ND optical detection and characterization

The localization and extinction spectroscopy of individual NDs were conducted using spatial modulation spectroscopy (SMS). This far-field microscopy/spectroscopy optical technique relies on the periodic displacement of a sample illuminated by a tightly focused light beam, which induces a modulation of the transmitted light power when a nano-object is present in the light beam.<sup>33,64</sup> SMS was initially employed to locate single NDs following their random deposition on the  $\text{Si}_3\text{N}_4$  membrane and, subsequently, for measuring their absolute extinction cross-section  $\sigma_{\text{ext}}$  as a function of the illumination wavelength  $\lambda$  and light polarization angle  $\theta$ . SMS experiments were performed using a light source spanning the 375–1040 nm wavelength range, obtained by combining a tunable femtosecond Ti:sapphire oscillator (emitting  $\lambda = 690$ –1040 nm pulses at a repetition frequency of  $f_{\text{rep}} = 80$  MHz) with a visible optical parametric oscillator and a frequency-doubling BBO crystal. The light beam delivered by this source was focused on the sample by a  $100\times$  microscope objective, resulting in nearly diffraction-limited spot sizes with a full-width at half-maximum of approximately  $0.7\lambda$ . Control over the direction of the beam linear polarization was achieved using a wire grid polarizer. Spatial modulation of the sample was performed at  $f = 1.5$  kHz frequency with 300 nm modulation amplitude and lock-in detection at  $2f$ .

#### 4.3. Time-resolved experiments

The transient optical response of individual NDs was measured using single-particle femtosecond pump-probe spectroscopy,<sup>36,65</sup> an approach based on the illumination of the investigated nanoparticle, previously detected by SMS, with two spatially overlapping, tightly focused and time-delayed femtosecond pump and probe light pulses. Time-resolved measurements on individual NDs were performed by combining the SMS microscope with a two-color pump-probe setup based on the femtosecond laser source described above, delivering  $\sim 150$  fs pulses. The oscillator pulse train was split in two parts to generate the pump and probe beams. The pump beam was produced using second harmonic generation (yielding  $\lambda_{\text{pp}}$  in the 375–510 nm range), whereas the probe beam was either the signal from the Ti:sapphire oscillator (with  $\lambda_{\text{pr}} = 750$ –1020 nm in this case) or the output of the optical parametric oscillator ( $\lambda_{\text{pr}} = 500$ –730 nm, with  $\lambda_{\text{pp}} = 410$  nm). To improve signal to noise ratio, a mechanical chopper operating

at 30 kHz was used for pump power modulation. The pump-induced relative changes of the probe beam transmission,  $\Delta T_{\text{r}}/T_{\text{r}}$ , were then measured using synchronous detection as a function of the time interval separating the pump and probe pulses, controlled by a mechanical delay line. This raw measured signal is directly related to the transient changes of the extinction cross-section  $\sigma_{\text{ext}}(\lambda_{\text{pr}})$  of the investigated nano-object at probe wavelength  $\lambda_{\text{pr}}$  via  $\Delta T_{\text{r}}/T_{\text{r}} = -\Delta\sigma_{\text{ext}}(\lambda_{\text{pr}})/S_{\text{pr}}$ , with  $S_{\text{pr}} = \pi d_{\text{fwhm}}^2/(4 \ln 2)$  representing the area of the probe spot (which can be estimated by analysis of SMS images) and  $d_{\text{fwhm}}$  its full-width at half-maximum.<sup>65</sup>

#### 4.4. Thermal simulations

Modeling of the ND linear optical response, cooling dynamics and transient optical response was performed using a finite-element modeling (FEM) commercial software. In all these simulations, Gold NDs were described as circular cylinders characterized by their thickness  $h$  and diameter  $D$ , and the 15 nm thick  $\text{Si}_3\text{N}_4$  membrane supporting them was explicitly included. Thermal simulations were done considering a cylindrical membrane with a  $D_{\text{m}} = 2 \mu\text{m}$  diameter, with thermal insulation boundary conditions on its upper and lower circular bases, and constant temperature ones on its lateral surface. 2D axisymmetric simulations exploiting the rotational symmetry of the considered geometry were performed, allowing to greatly reduce the required computational times. 2.49 and 2.13  $\text{MJ m}^{-3} \text{K}^{-1}$  values were used for the specific heats of Au and  $\text{Si}_3\text{N}_4$ . A 317  $\text{W m}^{-1} \text{K}^{-1}$  value (bulk gold value) was used for the ND thermal conductivity. The heat conductivity of  $\text{Si}_3\text{N}_4$  and the thermal conductance at the Au- $\text{Si}_3\text{N}_4$  interface were left as free parameters. FEM was used to compute the frequency-domain response  $\tilde{h}(f)$  of a supported gold ND, *i.e.* the frequency- and position-dependent amplitudes and phases of the temperature oscillations following sinusoidal energy injection in the ND. The Fourier transform  $\tilde{\Delta T}(f)$  of the thermal dynamics induced by any time-dependent excitation process  $q(t)$ , of Fourier transform  $\tilde{q}(f)$ , can then be deduced from  $\tilde{h}(f)$  by computing  $\tilde{\Delta T}(f) = \tilde{h}(f)\tilde{q}(f)$ , allowing to deduce the corresponding temporal dynamics  $\Delta T(t)$  by reverse Fourier transform.<sup>37</sup>

#### 4.5. Optical and thermo-optical simulations

A simulation domain containing the ND and the  $\text{Si}_3\text{N}_4$  membrane with air above and below it, surrounded by a perfectly matched layer was considered for computing the optical response of gold NDs. Refractive indexes of 2.03 and 1 were used for  $\text{Si}_3\text{N}_4$  and air, respectively. The dielectric function  $\epsilon = \epsilon_1 + i\epsilon_2$  of bulk gold in the visible/near-infrared range can be written as the sum of interband (ib) and intraband (Drude-like) components as<sup>33,66,67</sup>  $\epsilon(\omega) = \epsilon^{\text{ib}}(\omega) + \epsilon^{\text{D}}(\omega) - 1 = \epsilon^{\text{ib}}(\omega) - \frac{\omega_{\text{p}}^2}{\omega(\omega + i\gamma)}$ , with  $\omega_{\text{p}}$  the plasma frequency and  $\gamma$  the optical scattering rate of the conduction electrons ( $\hbar\omega_{\text{p}} = 9.01$  eV and  $\hbar\gamma \approx 50$  meV for bulk gold). In this work, we used bulk  $\omega_{\text{p}}$  and  $\epsilon^{\text{ib}}$  values (the latter being deduced from Johnson





and Christy tables<sup>68</sup>) and  $h\gamma$  values larger (typically by  $\approx 100$  meV) than the bulk gold value, as required to reproduce the SPR widths measured on single nano-objects. This corresponds to taking into account additional non-radiative plasmon damping mechanisms in metal nano-objects as compared to the bulk metal case.<sup>69–72</sup> ND illumination by a linearly polarized plane wave was considered. Absorption and scattering cross-sections were deduced from the computed electric field profiles, and summed to yield the extinction one  $\sigma_{\text{ext}}$ . The  $\partial\sigma_{\text{ext}}/\partial\varepsilon_1$  and  $\partial\sigma_{\text{ext}}/\partial\varepsilon_2$  partial derivatives were deduced from these calculations by computing  $\sigma_{\text{ext}}$  with slightly modified  $\varepsilon_1$  or  $\varepsilon_2$  values and then performing discrete derivation.

The transient optical response of NDs induced by their thermal dynamics was computed by reproducing the previous calculations at various stages of the thermal dynamics, using non-uniform dielectric functions locally modified as compared to room-temperature Au and  $\text{Si}_3\text{N}_4$  values as  $\Delta\varepsilon_{1,2}(\vec{r}, t) = \frac{\partial\varepsilon_{1,2}}{\partial T_{\text{ND}}} \Delta T_{\text{ND}}(\vec{r}, t)$  and  $\Delta\varepsilon_{\text{m}}(\vec{r}, t) = \frac{\partial\varepsilon_{\text{m}}}{\partial T_{\text{m}}} \Delta T_{\text{m}}(\vec{r}, t)$ .  $\frac{\partial\varepsilon_{\text{m}}}{\partial T_{\text{m}}} = 10^{-4} \text{ K}^{-1}$  was used for  $\text{Si}_3\text{N}_4$ , while wavelength-dependent tables from ref. 53 were used for  $\frac{\partial\varepsilon_{1,2}}{\partial T_{\text{ND}}}$ .

## Conflicts of interest

There are no conflicts to declare.

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